

Description

The NX3008NBK uses advanced trench technology

to provide excellent $R_{\text{DS}(\text{ON})}\text{,}$ low gate charge and

operation with gate voltages as low as 2.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

General Features

 V_{DS} = 30V I_D =5A

 $R_{DS(ON)} < 40m\Omega @ V_{GS}=10V$

Application

Battery protection

Load switch Uninterruptible power supply

Package Marking and Ordering Information

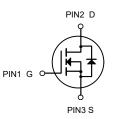
Product ID	Pack	Marking	Qty(PCS)
NX3008NBK	SOT-23	A09T	3000

Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Symbol	Parameter	Limit	Unit	
VDS	Drain-Source Voltage	30	V	
Vgs	Gate-Source Voltage	±12	V	
Ι _D	Drain Current-Continuous	5	А	
DM	Drain Current-Pulsed (Note 1)	14.4	A	
PD	P _D Maximum Power Dissipation		W	
TJ,TSTG	T _J ,T _{STG} Operating Junction and Storage Temperature Range		°C	
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	125	°C /W	







N-Channel MOSFET



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter Conditions		Min.	Тур.	Max.	Unit	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	30			V	
Provent	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =3A		33	40	mΩ	
Rds(on)		V _{GS} =4.5V , I _D =2A		55	75		
$V_{GS(th)}$	GS(th) Gate Threshold Voltage VGS=VDS , ID =250uA		0.4		1.2	V	
I	Drain-Source Leakage Current	V_{DS} =16V , V_{GS} =0V , T_{J} =25°C			1		
IDSS		V _{DS} =16V , V _{GS} =0V , T _J =55°C			5	uA	
Igss	Gate-Source Leakage Current	Source Leakage Current V _{GS} =±12V , V _{DS} =0V			±100	nA	
gfs	Forward Transconductance	V _{DS} =5V , I _D =3A		10.5		S	
Qg	Total Gate Charge (4.5V)			4.6			
Qgs	Gate-Source Charge	V _{DS} =15V , V _{GS} =4.5V , I _D =3A		0.7		nC	
Q_gd	Gate-Drain Charge			1.5			
T _{d(on)}	Turn-On Delay Time			1.6			
Tr	Rise Time	V_{DD} =10V , V_{GS} =4.5V , R_{G} =3.3 Ω I_{D} =3A		42			
T _{d(off)}	Turn-Off Delay Time			14		ns	
T _f	Fall Time			7			
Ciss	Input Capacitance			310			
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		49		pF	
Crss	Reverse Transfer Capacitance	ransfer Capacitance		35			

Diode Characteristics

Syn	mbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I	ls	Continuous Source Current ^{1,4}	V _G =V _D =0V , Force Current			3.6	А
V	/sd	Diode Forward Voltage ²	V _{GS} =0V , Is=1A , TJ=25°C			1.2	V

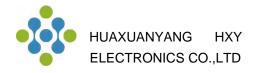
Note :

1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

2.The data tested by pulsed , pulse width $\,\leq\,$ 300us , duty cycle $\,\leq\,$ 2%

3. The power dissipation is limited by 150°C junction temperature

4. The data is theoretically the same as I_{D} and I_{DM} , in real applications , should be limited by total power dissipation.



Typical Characteristics

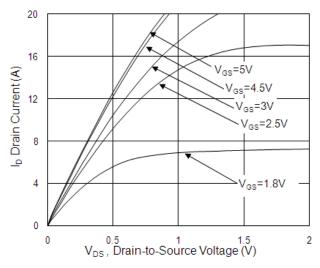


Fig.1 Typical Output Characteristics

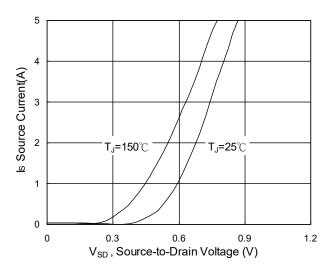


Fig.3 Forward Characteristics of Reverse

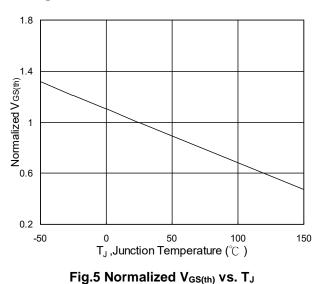


Fig.2 On-Resistance vs. Gate-Source Voltage

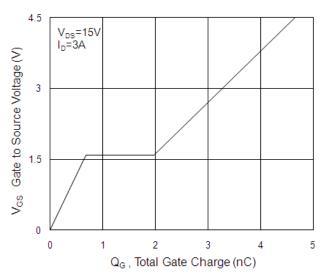


Fig.4 Gate-Charge Characteristics

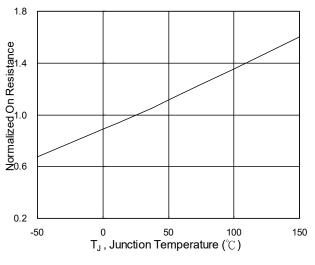
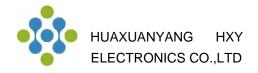


Fig.6 Normalized R_{DSON} vs. T_J



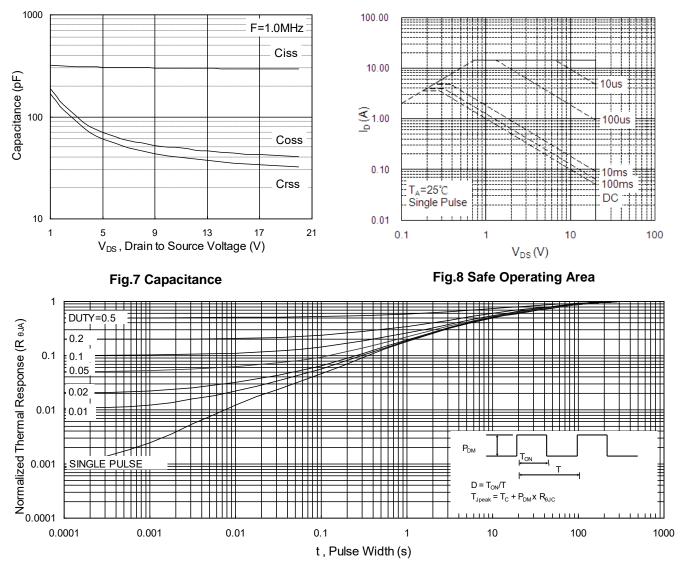


Fig.9 Normalized Maximum Transient Thermal Impedance

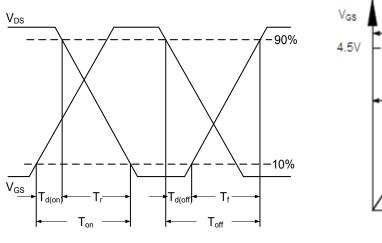
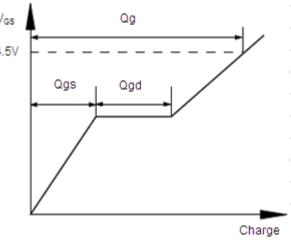


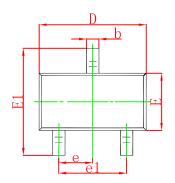
Fig.10 Switching Time Waveform

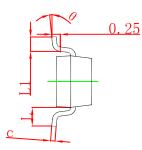


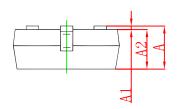




SOT-23 Package Outline Dimensions

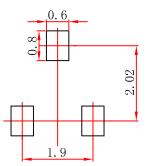






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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